

FEATURES

DB, DGV, DW, N, OR PW PACKAGE Operates From 1.65 V to 3.6 V (TOP VIEW) Max t_{pd} of 3.6 ns at 3.3 V OE [20 🛛 Vcc ±24-mA Output Drive at 3.3 V 1Q 🛛 2 19 🛛 8Q Bus Hold on Data Inputs Eliminates the Need 1D 3 18 🛛 8D for External Pullup/Pulldown Resistors 2D 🛛 7D 4 17 Latch-Up Performance Exceeds 100 mA Per 2Q 🛛 5 16 🛛 7Q JESD 78, Class II 3Q [6 15 🛛 6Q ESD Protection Exceeds JESD 22 3D 🛛 7 14 6D 4D 🛛 8 - 2000-V Human-Body Model (A114-A) 13 🛛 5D 4Q 9 12 5Q - 200-V Machine Model (A115-A) GND 11 1 CLK н 10 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This octal edge-triggered D-type flip-flop is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74ALVCH374 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels at the data (D) inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

T _A	PA	CKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP - N	Tube	SN74ALVCH374N	SN74ALVCH374N
		Tube	SN74ALVCH374DW	
	SOIC - DW	Tape and reel	SN74ALVCH374DWR	ALVCH374
-40°C to 85°C	SSOP - DB	Tape and reel	SN74ALVCH374DBR	VB374
		Tube	SN74ALVCH374PW	1/0074
	TSSOP - PW	Tape and reel	SN74ALVCH374PWR	– VB374
	TVSOP - DGV	Tape and reel	SN74ALVCH374DGVR	VB374

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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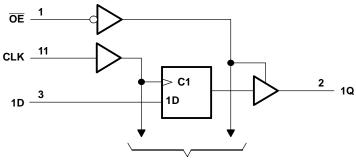
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FUNCTION TABLE

	INPUTS		OUTPUT
OE	CLK	D	Q
L	\uparrow	Н	Н
L	\uparrow	L	L
L	H or L	х	Q_0
Н	Х	Х	Z

LOGIC DIAGRAM (POSITIVE LOGIC)



To Seven Other Channels

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Output voltage range ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
		DB package		70	
		DGV package		92	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DW package		58	°C/W
		N package		69	
		PW package		83	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 4.6 V maximum.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.



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RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		1.65	3.6	V
		V _{CC} = 1.65 V to 1.95 V	$0.65 imes V_{CC}$		
V _{IH}	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.7		V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	
V _{IL}	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	
VI	Input voltage	· ·	0	V _{CC}	V
Vo	Output voltage		0	V _{CC}	V
	Oulput Voltage	V _{CC} = 1.65 V		-4	
		$V_{CC} = 2.3 V$		-12	mA
I _{OH}	High-level output current	$V_{CC} = 2.7 V$		-12	ША
		$V_{CC} = 3 V$		-24	
		V _{CC} = 1.65 V		4	
	Low lovel output ourrept	$V_{CC} = 2.3 V$		12	mA
I _{OL}	Low-level output current	$V_{CC} = 2.7 V$		12	ША
		$V_{CC} = 3 V$		24	
$\Delta t/\Delta v$	Input transition rise or fall rate			5	ns/V
T _A	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER	TEST CONDITIONS	V _{cc}	ΜΙΝ ΤΥ	(P ⁽¹⁾ MAX	UNIT
		I _{OH} = -100 μA	1.65 V to 3.6 V	V _{CC} - 0.2		
		I _{OH} = -4 mA	1.65 V	1.2		
		I _{OH} = -6 mA	2.3 V	2		
V _{ОН}			2.3 V	1.7		V
		I _{OH} = -12 mA	2.7 V	2.2		
			3 V	2.4		
		I _{OH} = -24 mA	3 V	2		
		I _{OL} = 100 μA	1.65 V to 3.6 V		0.2	
		I _{OL} = 4 mA	1.65 V		0.45	
		I _{OL} = 6 mA	2.3 V		0.4	
V _{OL}		10	2.3 V		0.7	V
		I _{OL} = 12 mA	2.7 V		0.4	
		I _{OL} = 24 mA	3 V		0.55	
I _I		$V_1 = V_{CC}$ or GND	3.6 V		±5	μA
		V ₁ = 0.58 V	1.65 V	25		
		V ₁ = 1.07 V	1.65 V	-25		
		V ₁ = 0.7 V	2.3 V	45		
I _{I(hold)}		V ₁ = 1.7 V	2.3 V	-45		μA
		V ₁ = 0.8 V	3 V	75		
		V ₁ = 2 V	3 V	-75		
		$V_1 = 0$ to 3.6 V ⁽²⁾	3.6 V		±500	
l _{oz}		$V_{O} = V_{CC}$ or GND	3.6 V		±10	μΑ
I _{CC}		$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	3.6 V		10	μA
∆l _{CC}		One input at V_{CC} - 0.6 V, Other inputs at V_{CC} or GND	3 V to 3.6 V		750	μΑ
	Control inputs		221		5	- 5
C _i	Data inputs	$V_{I} = V_{CC}$ or GND	3.3 V		6	pF
Co	Outputs	$V_{O} = V_{CC}$ or GND	3.3 V		7.5	pF
		1	1	1		

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(1) (2)

All typical values are at V_{CC} = 3.3 V, T_A = 25°C. This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		V_{CC} = 1.8 V ± 0.15 V		V_{CC} = 2.5 V \pm 0.2 V		V _{CC} = 2.7 V		V_{CC} = 3.3 V ± 0.3 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{clock}	Clock frequency				100		100		150	MHz
tw	Pulse duration, CLK high or low	3.8		3.3		3.3		3.3		ns
t _{su}	Setup time, data before CLK [↑]	3		1.8		2.1		1.8		ns
t _h	Hold time, data after CLK↑	1		0.5		0.5		0.5		ns



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{CC} = ± 0.1	V _{CC} = 1.8 V ± 0.15 V		V_{CC} = 2.5 V ± 0.2 V		2.7 V	V _{CC} = 3.3 V ± 0.3 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}					100		100		150		MHz
t _{pd}	CLK	Q	1.5	6.4	1	3.9		3.6	1.1	3.6	ns
t _{en}	ŌĒ	Q	3.6	8.1	2.1	5.6		5.3	1.6	5.2	ns
t _{dis}	OE	Q	2.7	7.9	0.9	4.5		4.4	1.2	4.5	ns

OPERATING CHARACTERISTICS

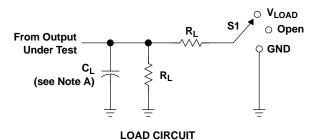
 $T_A = 25^{\circ}C$

	PARAMETE	R	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT	
<u> </u>	Power dissipation	Outputs enabled		44	46	50	۶F	
C _{pd}	capacitance per flip-flop	Outputs disabled	$C_{L} = 0, f = 10 \text{ MHz}$	24	26	29.5	рг	



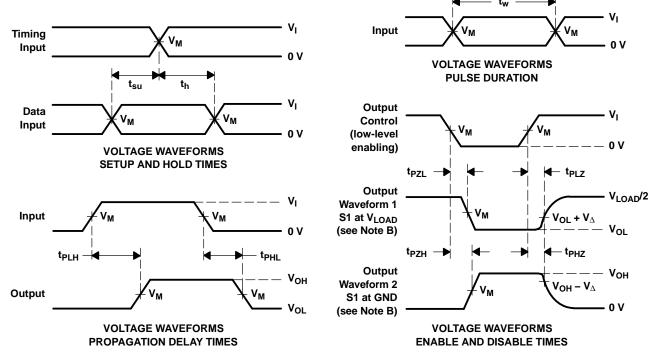
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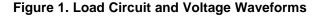
TEST	S1
t _{pd}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

Γ	V	IN	PUT	V	v	<u>^</u>	Р	V
	V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	C∟	RL	V_{Δ}
ſ	1.8 V \pm 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
	2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
	2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
	3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.





PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74ALVCH374DGVR	Active	Production	TVSOP (DGV) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374
SN74ALVCH374DGVR.B	Active	Production	TVSOP (DGV) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374
SN74ALVCH374DW	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH374
SN74ALVCH374DW.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH374
SN74ALVCH374PW	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374
SN74ALVCH374PW.B	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374
SN74ALVCH374PWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374
SN74ALVCH374PWR.B	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374
SN74ALVCH374PWRG4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374
SN74ALVCH374PWRG4.B	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB374

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE OPTION ADDENDUM

17-Jun-2025

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH374DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74ALVCH374PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74ALVCH374PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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PACKAGE MATERIALS INFORMATION

24-Jul-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH374DGVR	TVSOP	DGV	20	2000	353.0	353.0	32.0
SN74ALVCH374PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74ALVCH374PWRG4	TSSOP	PW	20	2000	353.0	353.0	32.0

TEXAS INSTRUMENTS

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24-Jul-2025

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74ALVCH374DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74ALVCH374DW.B	DW	SOIC	20	25	507	12.83	5080	6.6
SN74ALVCH374PW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74ALVCH374PW.B	PW	TSSOP	20	70	530	10.2	3600	3.5

PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0020A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0020A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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